

**Rectifier diodes
ultrafast, rugged**

BYV72EF series

GENERAL DESCRIPTION

Glass passivated dual epitaxial rectifier diodes in a full pack plastic envelope, featuring low forward voltage drop, ultra-fast recovery times, soft recovery characteristic and guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

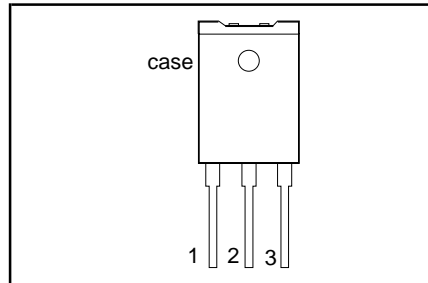
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V_{RRM}	Repetitive peak reverse voltage	100	150	200	V
		100	150	200	
V_F	Forward voltage	0.90	0.90	0.90	V
$I_{O(AV)}$	Output current (both diodes conducting)	20	20	20	A
t_{rr}	Reverse recovery time	28	28	28	ns
I_{RRM}	Repetitive peak reverse current per diode	0.2	0.2	0.2	A

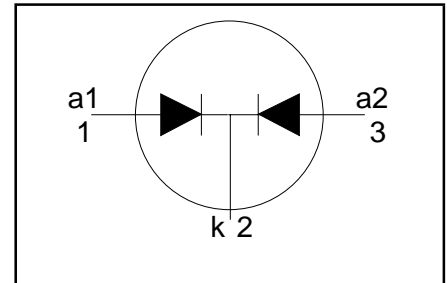
PINNING - SOT199

PIN	DESCRIPTION
1	anode 1 (a)
2	cathode (k)
3	anode 2 (a)

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
				-100	-150	-200	
V_{RRM}	Repetitive peak reverse voltage		-	100	150	200	V
V_{RWM}	Crest working reverse voltage		-	100	150	200	V
V_R	Continuous reverse voltage ¹		-	100	150	200	V
$I_{O(AV)}$	Output current (both diodes conducting) ²	square wave $\delta = 0.5; T_{hs} \leq 78^\circ\text{C}$	-	20			A
		sinusoidal $a = 1.57; T_{hs} \leq 78^\circ\text{C}$	-	20			A
$I_{O(RMS)}$	RMS forward current		-	20			A
I_{FRM}	Repetitive peak forward current per diode	$t = 25 \mu\text{s}; \delta = 0.5;$ $T_{hs} \leq 78^\circ\text{C}$	-	30			A
I_{FSM}	Non-repetitive peak forward current per diode	$t = 10 \text{ ms}$	-	150			A
		$t = 8.3 \text{ ms}$ sinusoidal; with reapplied $V_{RWM(max)}$	-	160			A
I^2t	I^2t for fusing	$t = 10 \text{ ms}$	-	112			A ² s
I_{RRM}	Repetitive peak reverse current per diode	$t_p = 2 \mu\text{s}; \delta = 0.001$	-	0.2			A
I_{RSM}	Non-repetitive peak reverse current per diode	$t_p = 100 \mu\text{s}$	-	0.2			A
T_{stg}	Storage temperature		-40	150			°C
T_j	Operating junction temperature		-	150			°C

1 $T_{hs} \leq 125^\circ\text{C}$ for thermal stability.

2 Neglecting switching and reverse current losses.

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ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_C	Electrostatic discharge capacitor voltage	Human body model; $C = 250 \text{ pF}$; $R = 1.5 \text{ k}\Omega$	-	8	kV

ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25 \text{ }^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{isol}	Repetitive peak voltage from all three terminals to external heatsink	R.H. $\leq 65 \%$; clean and dustfree	-		2500	V
C_{isol}	Capacitance from T2 to external heatsink	$f = 1 \text{ MHz}$	-	22	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-hs}$	Thermal resistance junction to heatsink	both diodes conducting with heatsink compound without heatsink compound per diode	-	-	4.0 8.0	K/W K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	with heatsink compound without heatsink compound in free air	-	- 35	5.0 9.0 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_j = 25 \text{ }^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage (per diode)	$I_F = 15 \text{ A}$; $T_j = 150 \text{ }^\circ\text{C}$ $I_F = 15 \text{ A}$ $I_F = 30 \text{ A}$	-	0.83 0.95 1.00	0.90 1.05 1.20	V V V
I_R	Reverse current (per diode)	$V_R = V_{RWM}$; $T_j = 100 \text{ }^\circ\text{C}$ $V_R = V_{RWM}$	-	0.5 10	1 100	mA μA

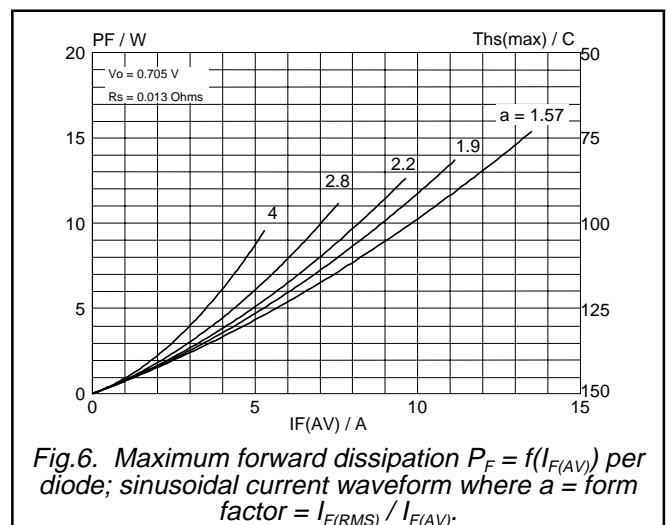
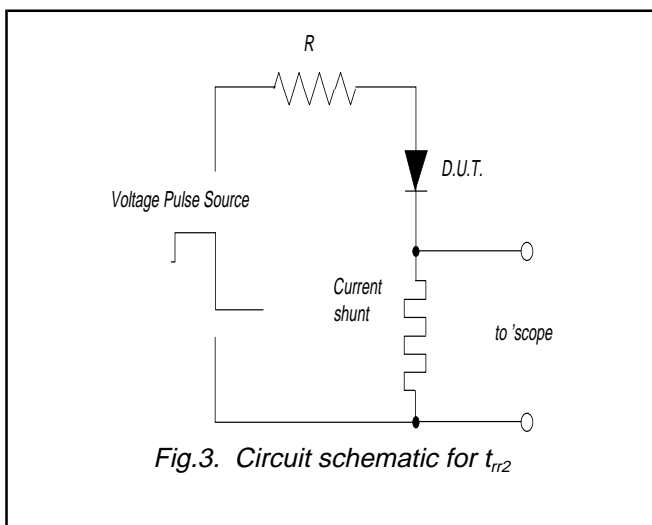
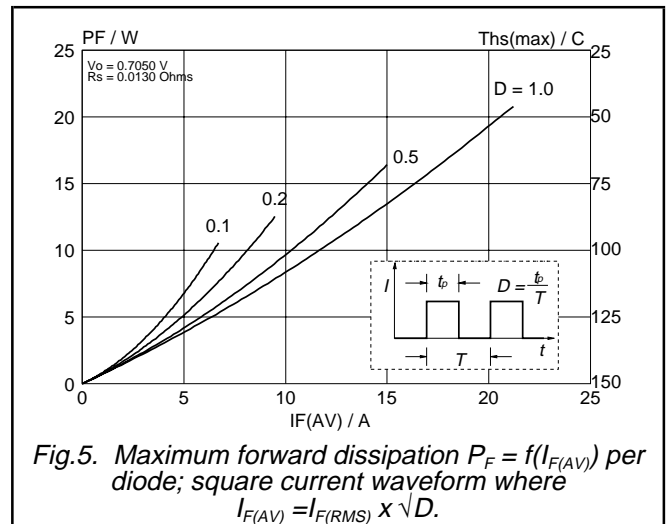
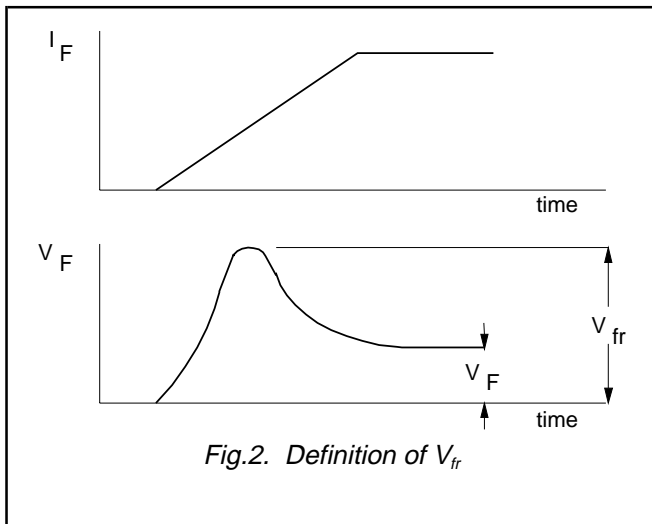
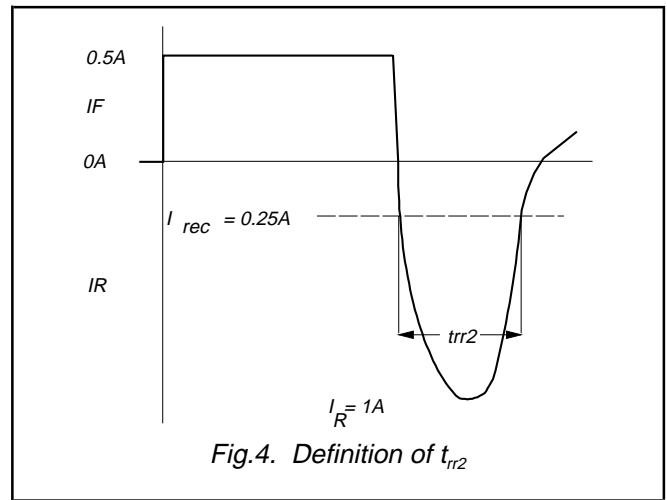
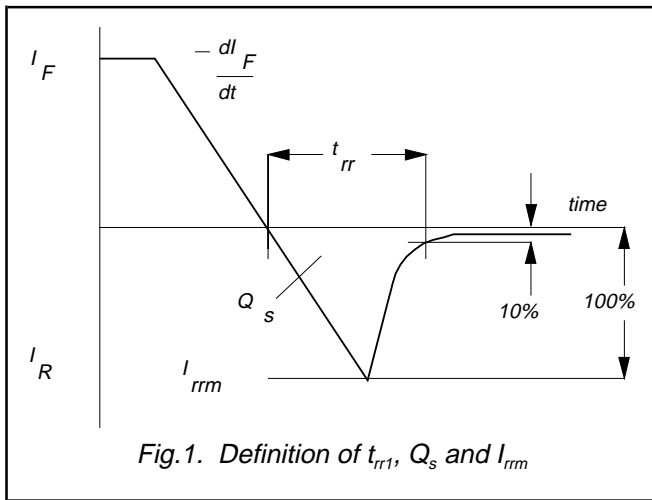
DYNAMIC CHARACTERISTICS

 $T_j = 25 \text{ }^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q_s	Reverse recovery charge (per diode)	$I_F = 2 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 20 \text{ A}/\mu\text{s}$	-	6	15	nC
t_{rr1}	Reverse recovery time (per diode)	$I_F = 1 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 100 \text{ A}/\mu\text{s}$	-	20	28	ns
t_{rr2}	Reverse recovery time (per diode)	$I_F = 0.5 \text{ A}$ to $I_R = 1 \text{ A}$; $I_{rec} = 0.25 \text{ A}$	-	13	22	ns
V_{fr}	Forward recovery voltage (per diode)	$I_F = 1 \text{ A}$; $di_F/dt = 10 \text{ A}/\mu\text{s}$	-	1	-	V

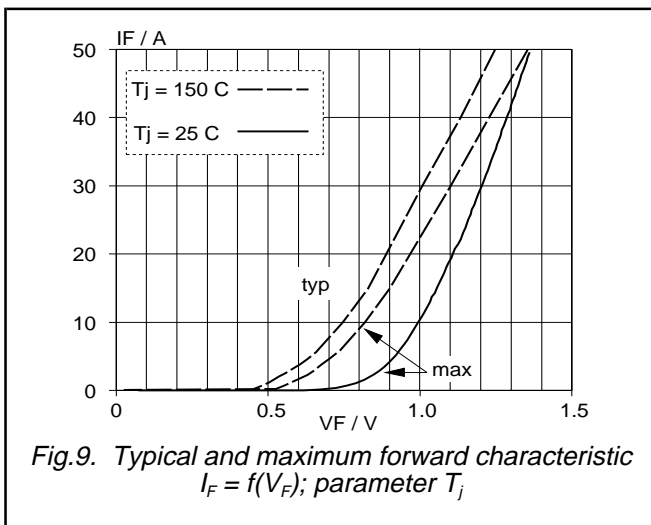
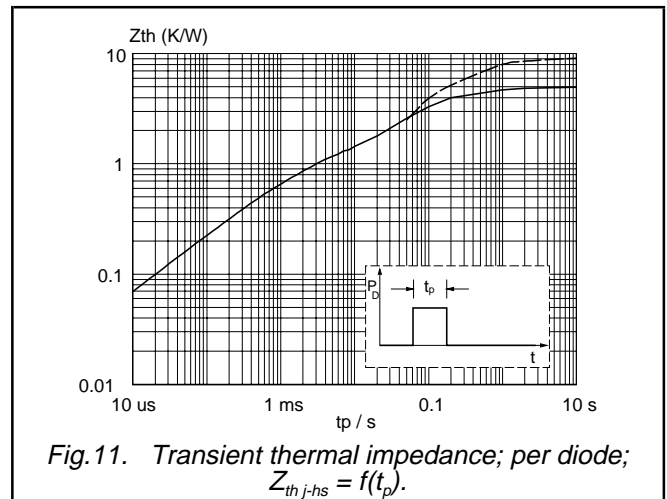
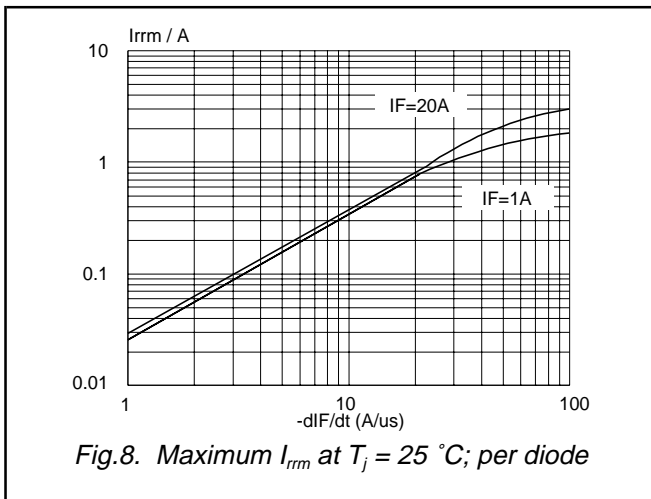
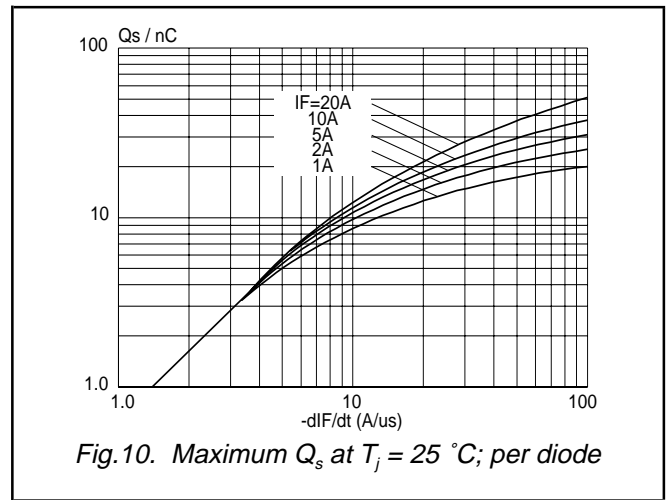
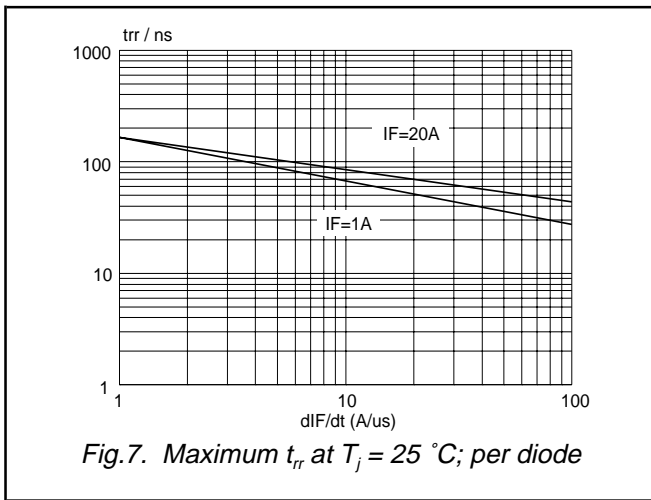
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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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